## NSN 5961-00-503-4861

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-503-4861 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 1.500 inches **Overall Height:** 0.220 inches **Overall Width:** 0.140 inches **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 68.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 40.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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